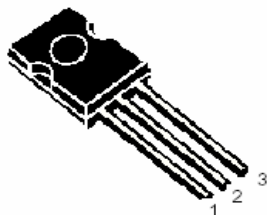


**NPN SILICON POWER TRANSISTOR**

**CFD13003**



PIN 1: BASE  
 PIN 2: COLLECTOR  
 PIN 3: EMITTER

**TO-126FP**  
**Plastic Package**

**Applications**

Suitable for Lighting, Switching Regulator and Motor Control

**ABSOLUTE MAXIMUM RATINGS**

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Base Voltage	$V_{CBO}$	600	V
Collector Emitter (sus) Voltage	$V_{CEO}$	400	V
Emitter Base Voltage	$V_{EBO}$	9.0	V
Collector Current Continuous	$I_C$	2.5	A
Peak (1)	$I_{CM}$	4.0	A
Base Current Continuous	$I_B$	0.75	A
Peak (1)	$I_{BM}$	1.5	A
Emitter Current Continuous	$I_E$	2.25	A
Peak (1)	$I_{EM}$	4.5	A
Power Dissipation at $T_a=25^\circ\text{C}$	$P_D$	1.4	W
Derate Above $25^\circ\text{C}$		11.2	mW/ $^\circ\text{C}$
Power Dissipation at $T_c=25^\circ\text{C}$	$P_D$	45	W
Derate Above $25^\circ\text{C}$		360	mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_j, T_{stg}$	- 65 to+150	$^\circ\text{C}$

**THERMAL RESISTANCE**

Junction to Case	$R_{th(j-c)}$	2.77	$^\circ\text{C}/\text{W}$
Junction to Ambient	$R_{th(j-a)}$	89	$^\circ\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purpose: 1/8" from Case for 5 Seconds	$T_L$	275	$^\circ\text{C}$

(1) Pulse Test: Pulse Width=5ms, Duty Cycle=10%

**ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$  Unless Specified Otherwise)**

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Base Voltage	$V_{CBO}$	$I_C=1\text{mA}, I_E=0$	600	-	-	V
Collector Emitter (sus) Voltage	$*V_{CEO(sus)}$	$I_C=10\text{mA}, I_B=0$	400	-	-	V
Collector Cut-Off Current	$I_{CBO}$	$V_{CB}=600\text{V}, I_E=0$ $V_{CB}=600\text{V}, I_E=0, T_c=100^\circ\text{C}$	-	-	1.0 5.0	mA mA
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB}=9\text{V}, I_C=0$	-	-	1.0	mA

\*Pulse Test: PW=300ms, Duty Cycle=2%

CFD13003Rev 300905D

ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$  Unless Specified Otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
DC Current Gain	$*h_{FE}$	$**I_C=0.5\text{A}, V_{CE}=5\text{V}$	11	-	30	
		$I_C=1\text{A}, V_{CE}=5\text{V}$	5	-	25	
Collector Emitter Saturation Voltage	$*V_{CE(sat)}$	$I_C=0.5\text{A}, I_B=0.1\text{A}$	-	-	0.5	V
		$I_C=1\text{A}, I_B=0.25\text{A}$	-	-	1.0	V
		$I_C=1.5\text{A}, I_B=0.5\text{A}$	-	-	2.5	V
		$I_C=1\text{A}, I_B=0.25\text{A}, T_c=100^\circ\text{C}$	-	-	1.0	V
Base Emitter Saturation Voltage	$*V_{BE(sat)}$	$I_C=0.5\text{A}, I_B=0.1\text{A}$	-	-	1.0	V
		$I_C=1\text{A}, I_B=0.25\text{A}$	-	-	1.2	V
		$I_C=1\text{A}, I_B=0.25\text{A}, T_c=100^\circ\text{C}$	-	-	1.1	V

## DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Current Gain Bandwidth Product	$f_T$	$I_C=100\text{mA}, V_{CE}=10\text{V},$ $f=1\text{MHz}$	4.0	-	-	MHz
Output Capacitance	$C_{ob}$	$V_{CB}=10\text{V}, f=0.1\text{MHz}$	-	21	-	pF

## SWITCHING TIME

Turn On Time	$t_{on}$	$V_{CC}=125\text{V}, I_C=1\text{A}, I_{B1}=0.2\text{A},$ $I_{B2}=0.2\text{A}$			1.1	$\mu\text{s}$
Storage Time	$t_{stg}$				4.0	$\mu\text{s}$
Fall Time	$t_s$				0.7	$\mu\text{s}$

**\*\*  $h_{FE}$  Classification:-**

Note:- Product is pre selected in DC current gain (Groups A to F). CDIL reserves the right to ship any of the groups according to production availability.	<b>A</b>	<b>B</b>	<b>C</b>	<b>E</b>	<b>F</b>
	11-16	15-19	18-22	21-25	24-30
MARKING	CFD	CFD	CFD	CFD	CFD
	13003A	13003B	13003C	13003E	13003F
	XY	XY	XY	XY	XY

\*Pulse Test:- PW=300ms, Duty Cycle=2%

### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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**Continental Device India Limited**

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119

e-mail [email@cdil.com](mailto:email@cdil.com) [www.cdilsemi.com](http://www.cdilsemi.com)